Superelasticity in Polycrystalline Ni-Mn-Ga-Fe Microwires Fabricated by Melt-extraction

Yanfen Liu,a,b Xuexi Zhang,c Jingshun Liu,c Dawei Xing,c
Hongxian Shen,a Dongming Chen,a Jianfei Sun*c

aSchool of Materials Science and Engineering, Harbin Institute of Technology, Harbin 150001, China
bDepartment of physics, Qiqihar University, Qiqihar 161006, China
cSchool of Materials Science and Engineering, Inner Mongolia University of Technology, Hohhot 010051, China

Received: September 9, 2014; Revised: May 12, 2015

Ni51Mn26.4Ga17.7Fe15 microwires with grain size of 1-3 micron were successfully fabricated by melt-extraction. The superelastic effects in the microwires under various temperatures and loads were systematically demonstrated. The as-extracted microwires displayed partial superelasticity when attended at relatively high temperature. The critical stress for stress-induced martensite formation increases linearly with temperature and follows the Clausius-Clapeyron relationship. The temperature dependence of the as-extracted polycrystalline Ni51.4Mn26.4Ga17.7Fe15 microwires is 16.4 MPa/K, which is higher compared with Ni-Mn-Ga single crystals. In addition, the as-extracted microwires display excellent shape memory behavior with the recovery strain and recovery ratio of 1.26% and 86%, respectively, when the total strain reaches 1.47% at 310 K.

Keywords: melt-extraction, Ni-Mn-Ga-Fe microwires, superelasticity, stress-induced martensitic transformation

1. Introduction

Ni-Mn-Ga shape memory alloys (SMAs) (a type of Heusler alloys) show great potential in actuators and sensors due to their unique shape memory effect (SME), superelastic effect (SE) and high magnetic-field induced strains (MFIS). The superelasticity of SMAs arises from a reversible stress-induced martensitic transformation (SIMT) when loading or unloading at temperature regimes higher than martensitic transformation temperature (MT). Chernenko et al. reported the SE associated with the reversible SIMT in single crystalline Ni51.1Mn26.4Ga17.7, Ni51.2Mn11Ga17.7, and Ni49.4Mn27.5Ga22.5 alloys. The temperature dependence of the critical SIMT stress in Ni-Mn-Ga alloys follows a linear function, which can be deduced from both general thermodynamic expression and Landau theory. In polycrystalline Ni49.9Mn25.3Ga15.1 microwires, Qian et al. reported that SIMT stress increased linearly with the temperature and could be described by Clausius-Clapeyron relationship.

The application of ternary Ni-Mn-Ga SMAs is limited because of their low martensitic transformation temperature and high intergranular fracture tendency. Thus, various options such as a fourth element doping and grain refinement have been used to improve the properties of Ni-Mn-Ga alloys. The brittleness of Ni-Mn-Ga alloy might be effectively improved by doping fourth transitional elements such as Fe6,7, Co5, Cu10-11 and Y10 or rare earth elements such as Gd12, Dy13 and Tb14. A recent report revealed that the brittleness and SME of Ni-Mn-Ga alloys were significantly improved through Fe-doping15. Moreover, grain refinement by rapid solidification technology is also an effective way to improve the SME and brittleness4,16,17 of Ni-Mn-Ga alloys. For example, Ni-Mn-Ga fibers with fine gains of 1-3 microns showed enhanced superelasticity and shape memory properties compared with the corresponding bulk alloys4.

In this work Ni51.4Mn26.4Ga17.7Fe15 microwires with diameters of ~30-40 μm and lengths of ~10 cm were fabricated by melt-extraction method. The superelasticity of Fe-doped polycrystalline Ni-Mn-Ga microwires was systematically investigated.

2. Experimental Details

An ingot with a nominal composition of Ni51.4Mn26.4Ga17.7Fe15 (at. %) was firstly prepared by arc-melting with pure Ni (99.99%), Mn (99.99%), Ga (99.99%), and Fe (99.99%) elements under argon atmosphere. The ingot was then re-melted and extracted into microwires by a melt-extraction device. The melt-extraction process was carried out using a copper wheel with a diameter of 320 mm and wheel-edge angle of 60°. During the melt-extraction, the wheel flange linear velocity and feeding rate of the molten material were fixed at 30 m/s and 30 μm/s, respectively.

The surface morphologies of the microwires were investigated on a scanning electron microscope (SEM-Helios Nanolab600i). Martensite transformation temperatures of the microwire were obtained with a Magnetic Property Measurement System (SQUID-VSM) made by Quantum Design. The temperatures dependence of magnetization (M-T) curves were measured at a constant external magnetic field of 10 Oe and heating/cooling rates of 5 K/min.
The samples for the tensile tests have uniform diameters and gauge lengths of 2 mm. The tensile stress-strain curves of the microwires were obtained using a dynamic mechanical analyzer (DMA Q800). The microwire was firstly heated to 353 K (slightly higher than \( A_f \)) with a rate of 5 K/min and kept at this temperature for 12 min. Then the microwire was cooled to the test temperature (slightly higher than \( M_s \)) and was subjected to a tensile loading-unloading cycle. A series of experimental methods for superelastic effect tests were formulated and shown in Table 1.

### 3. Results and Discussion

The morphology of an as-extracted microwire is shown in Figure 1a. The microwire has a plane surface (marked as A) and free circular surface (marked as B). The plane surface was formed by contact and solidification of the melt on the copper wheel. When the extracted melt filament left the copper wheel, the remaining melt grew from A to the free surface B (grew directions were marked with uni-directional arrows). The resulting cellular grain sizes on the free surface B are \( \sim \)1-3 μm.

A typical stress-strain (SS) curve during a cycle with loading/unloading processes and experimental parameters is shown in Figure 1b. During loading, the starting stress (\( \sigma_{M_s} \)) and finishing stress (\( \sigma_{M_f} \)) of the SIMT were denoted as A and B in Figure 1b. Upon unloading, the starting stress (\( \sigma_{A_s} \)) and finishing stress (\( \sigma_{A_f} \)) of the reverse austenite transformation were denoted as D and E. The enclosed area of OABDEFO represents the hysteretic energy (\( \Delta W \)) during a loading and unloading cycle. In Figure 1b, \( \sigma_u \), \( \varepsilon_e \), and \( \varepsilon_{res} \) are the maximum strain, recoverable elastic strain and residual strain, respectively. The superelastic strain \( \varepsilon_{SE} \) can be expressed by \( \varepsilon_{SE} = \varepsilon_u - \varepsilon_e - \varepsilon_{res} \). OA, AB, BC are respectively expressed as austenitic state, transformation state from austenite to martensite and martensitic state during loading process, and DBC, DE, EF are respectively expressed as martensitic state, transformation state from martensite to austenite and the austenitic state during the unloading process. The slopes of linear OA and BC are the deformation modulus of austenitic and martensitic state, respectively.

Figure 2 shows the temperatures dependence of magnetization (\( M-T \)) curves for the Ni\(_{48}\)Mn\(_{26.4}\)Ga\(_{19.7}\)Fe\(_{5.9}\) microwires at a constant external magnetic field of 10 Oe. The martensite starting (\( M_s \)) and finishing (\( M_f \)) temperatures were 305 and 292 K during cooling process, respectively while the austenite starting (\( A_s \)) and finishing (\( A_f \)) temperatures were respectively 301 and 311.5 K during heating process. The thermal hysteresis (\( \Delta T = A_f - M_s \)) was determined to be \( \sim \)6.5 K.

Figure 3 displays the SS curves obtained based on the experimental methods Group 1# (as shown in Table 1), every superelastic experiment tests is repeated four times. The SS curves overlapped during the four cycles which revealed a good stability of the superelastic cycles. As a result, the critical stresses for the phase transformation kept intact.

### Table 1. Superelastic tests of Ni-Mn-Ga-Fe microwires.

<table>
<thead>
<tr>
<th>Group</th>
<th>Loading method</th>
<th>Loading/unloading rate (N/min)</th>
<th>Test temperature (K)</th>
</tr>
</thead>
<tbody>
<tr>
<td>1#</td>
<td>Loaded to 275MPa, unloaded and repeated 4 times</td>
<td>0.04/0.075</td>
<td>317</td>
</tr>
<tr>
<td>2#</td>
<td>Loaded to 375MPa, unloaded and repeated 3 times</td>
<td>0.04/0.075</td>
<td>306,308,310,315</td>
</tr>
<tr>
<td>3#</td>
<td>Loaded to 250, 313, 375 MPa, unloaded and repeated 3 times</td>
<td>0.04/0.075</td>
<td>310</td>
</tr>
</tbody>
</table>

Figure 1. (a) SEM image of polycrystalline Ni\(_{48}\)Mn\(_{26.4}\)Ga\(_{19.7}\)Fe\(_{5.9}\) fibers at room temperature. (b) Typical stress-strain curve.

Figure 2. Magnetization versus temperature (\( M-T \)) curves for Ni\(_{48}\)Mn\(_{26.4}\)Ga\(_{19.7}\)Fe\(_{5.9}\) microwires.
The SS curves of an as-extracted Ni_{48}Mn_{26.4}Ga_{19.7}Fe_{5.9} microwire at various temperatures of 306, 308, 310 and 315 K are plotted in Figure 4a (based on Group 2# of experimental methods in Table 1). It is clearly shown that the microwire exhibited SE at these temperatures. The corresponding strains $\varepsilon_u$, $\varepsilon_{res}$, and $\varepsilon_{SE}$ as functions of temperatures are displayed in Figure 4b. The maximum strain achieved in the Ni$_{48}$Mn$_{26.4}$Ga$_{19.7}$Fe$_{5.9}$ microwire was ~1.49%, which is much smaller than that in single-crystalline Ni$_{54}$Mn$_{25}$Ga$_{21}$ alloys (~10% for compressed state$^{14}$), but close to that in polycrystalline Ni-Mn-Ga microwires (~2.7%$^{4}$). The maximum strain that can be achieved in polycrystalline Ni-Mn-Ga-Fe microwires is limited by the intergranular fracture during loading-unloading cycles. Figure 4b shows that $\varepsilon_u$ and $\varepsilon_{res}$ decrease with the increase of temperatures. However, $\varepsilon_{SE}$ increases with temperature until a maximum point ($\varepsilon_{max}$= 0.54%) is reached. Such behavior has also been found in Cu-based SMAs$^{18}$. The maximum recoverable ratio in Ni-Mn-Ga-Fe microwires is ~95.6% at 315 K as described in Figure 4b, which is much higher than Ni-Mn-Ga alloys (~63%)$^{15}$ and comparable to Ni$_{49.5}$Mn$_{28.6}$Ga$_{21.5}$ microwire$^4$.

It can be seen from Figure 4b that the strain recovery ratio increases with temperature and the residual strain decreases from 0.45% at 306K to 0.05% at 315 K. The higher recovery ratio at higher temperatures may be attributed to the higher density of elastic energy accumulated in the substrate during the process of SIMT$^1$. The elastic energy and thermal energy act as the driving force for the strain recovery. Therefore, the residual strain decreases but recovery ratio increases with temperature.

Figure 4c shows plots of temperature dependence of deformation modulus. Contrary to the austenite, the reduced

![Figure 3. Tensile stress-strain curves under the same loading at austenite state (317 K) for as-extracted Ni$_{48}$Mn$_{26.4}$Ga$_{19.7}$Fe$_{5.9}$ microwires.](image)

![Figure 4. (a) Stress-strain curves at different temperatures in one cycle tensile test, (b) Temperature dependence of strain and recovery ratio, (c) Temperature dependent of deformation modulus and (d) Critical stress as a function of temperature of as-extracted Ni$_{48}$Mn$_{26.4}$Ga$_{19.7}$Fe$_{5.9}$ microwires.](image)
modulus of martensite with temperature can be found, which may be attributed to the softening of lattice vibration (provided by acoustic mode) during phase transformation. The reduced deformation modulus in the forward phase transformation correspond to the localized soft mode theory (LSMT)\(^\text{19}\).

Figure 4d shows the temperature dependence of critical stress for SIMT in the as-extracted Ni\(_{48}\)Mn\(_{26.4}\)Ga\(_{19.7}\)Fe\(_{5.9}\) microwires. From the \(\sigma-T\) curve, it is found that the critical stress exhibited a linear relationship with temperature. The slopes (\(d\sigma/dT\)) of the \(\sigma_{Ms}-T\) and \(\sigma_{Af}-T\) curves were determined to be ~16.4 and ~16.2 MPa/K from Figure 4d. The slopes in the present Fe-doping Ni-Mn-Ga microwires are larger than that in Ni-Mn-Ga single crystals (~5.2 MPa/K along [110])\(^3\), which may be related to small grains (diameter ~1-3 \(\mu\)m) created by rapid solidification during melt-extraction (see Figure 1a). In addition, the critical stress of Ni\(_{48}\)Mn\(_{26.4}\)Ga\(_{19.7}\)Fe\(_{5.9}\) microwires showed higher temperature dependence than that in Ni\(_{49.5}\)Mn\(_{28.6}\)Ga\(_{21.5}\) microwires\(^4\) as well, which may be attributed to the solution strengthening effect of Fe.

Figure 5a shows tensile stress-strain curves at 310 K under different loading-unloading cycles (the loadings were 250 MPa, 313 MPa and 375 MPa, respectively, based on the Group 3\# of experimental methods as shown in Table 1). These stress-strain curves overlapped during loading, displaying a well reproducibility during SIMT process. During unloading process, the slope of the curve decreased with increasing loads, revealing the reduced critical stress for austenite transformation with the increasing loads. Figure 5b shows recovery strains and recovery ratios at different total strains. The strain recovery ratios are 85.2\%, 85.6\%, 86\% under loads of 250, 313 and 375 MPa, corresponding to total strains of 0.951, 1.24, 1.47\%. The slightly increased recovery strain and recovery ratio with the increase of total strain are consistent with the increased stored elastic energy at higher loads.

4. Conclusions

Fine grain polycrystalline Ni\(_{48}\)Mn\(_{26.4}\)Ga\(_{19.7}\)Fe\(_{5.9}\) microwires were prepared by melt-extraction and their superelastic effects were conducted. The main conclusions are summarized as follows:

1) The martensite transformation starting temperature (\(M_s\)) in Fe-doped Ni-Mn-Ga microwires is ~305 K, which is close to the room temperature. The critical stress of SIMT increases linearly with increasing temperature, following the Clausius-Clapeyron relationship.

2) The temperature dependence of SE critical stress in Ni\(_{48}\)Mn\(_{26.4}\)Ga\(_{19.7}\)Fe\(_{5.9}\) microwires is 16.4 MPa/K, which is much higher than Ni-Mn-Ga bulk single-crystals and polycrystalline microwires.

3) The recovery stress increase with increasing temperature and the maximum strain recovery ratio is ~95.6\% at 315 K.

Acknowledgements

This work was financially supported by National Natural Science Foundation of China (NSFC) under grant Nos. 51001038 and Ministry of Science and Technology Bureau of Harbin under grant No. 2011RFQXG001. J.S.L. acknowledges the financial support provided by the National Natural Science Foundation of China (NSFC) under grant Nos. 51401111 and 51561026, Natural Science Foundation of Inner Mongolia Autonomous Region of China under grant Nos. 2014BS0503, and Scientific Research Foundation of the Higher Education Institutions (SRFHEI) of Inner Mongolia Autonomous Region of China under grant Nos. NJZY14062.

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